

## Features

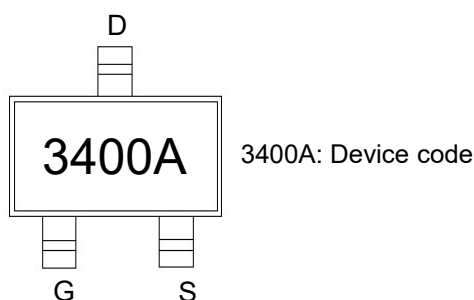
- Trench Power LV MOSFET technology
- High density cell design for low  $R_{DS(ON)}$
- High Speed switching

## Application

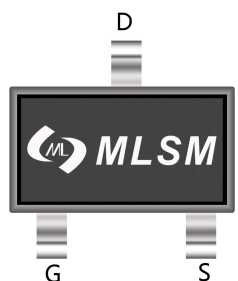
- Battery protection
- Load switch
- Power management

## Product Summary

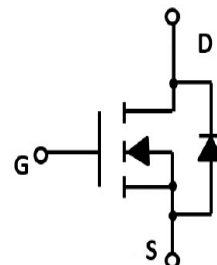
| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
|----------|------------------|-----------|
| 30V      | 28mΩ@10V         | 5.8A      |
|          | 33mΩ@4.5V        |           |



Marking and pin assignment



SOT-23-3L top view



Schematic diagram



Pb-Free



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

### Common Ratings (TC=25°C Unless Otherwise Noted)

|                  |                                  |         |            |    |
|------------------|----------------------------------|---------|------------|----|
| V <sub>DS</sub>  | Drain-Source Breakdown Voltage   |         | 30         | V  |
| V <sub>GS</sub>  | Gate-Source Voltage              |         | ±12        | V  |
| T <sub>J</sub>   | Maximum Junction Temperature     |         | 150        | °C |
| T <sub>STG</sub> | Storage Temperature Range        |         | -50 to 155 | °C |
| I <sub>S</sub>   | Diode Continuous Forward Current | Tc=25°C | 5.8        | A  |

### Mounted on Large Heat Sink

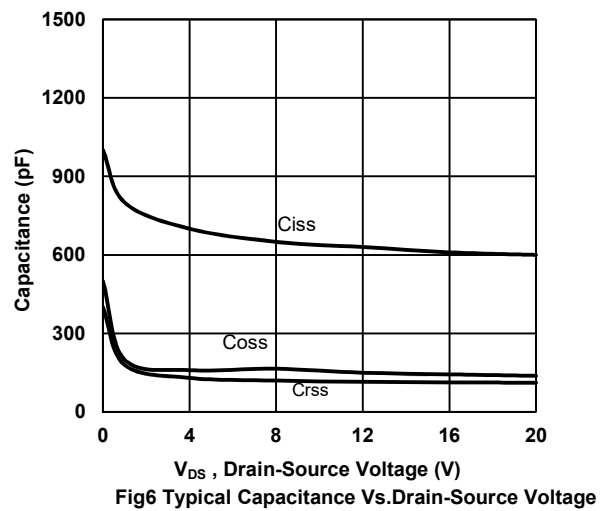
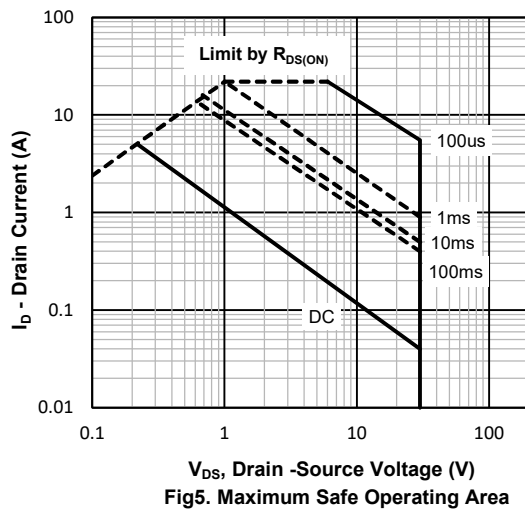
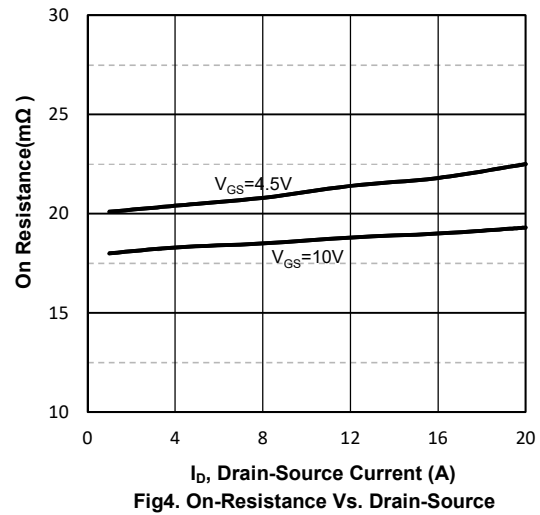
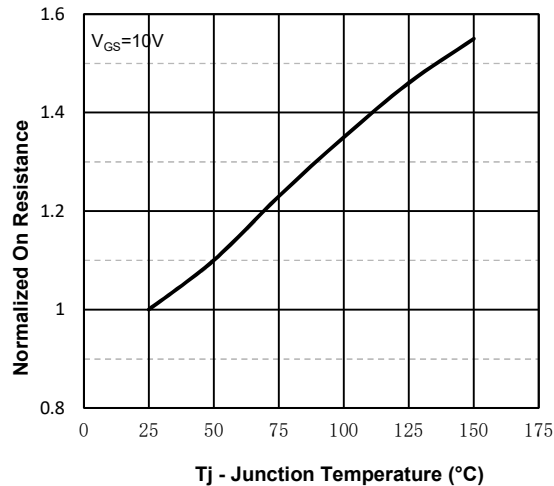
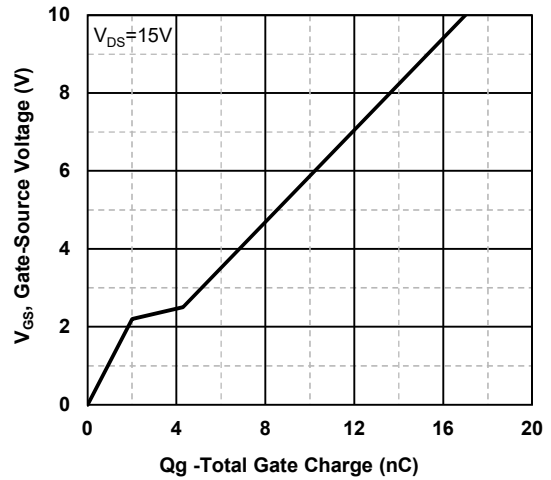
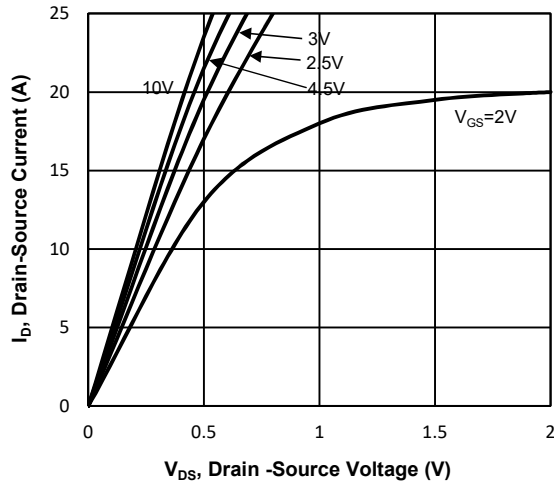
|                 |                                     |                        |     |      |
|-----------------|-------------------------------------|------------------------|-----|------|
| $I_{DM}$        | Pulse Drain Current Tested          | $T_c=25^\circ\text{C}$ | 23  | A    |
| $I_D$           | Continuous Drain Current            | $T_c=25^\circ\text{C}$ | 5.8 | A    |
| $P_D$           | Maximum Power Dissipation           | $T_c=25^\circ\text{C}$ | 1.2 | W    |
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient |                        | 104 | °C/W |

## Ordering Information (Example)

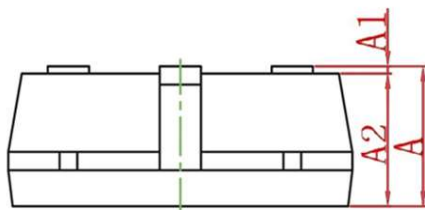
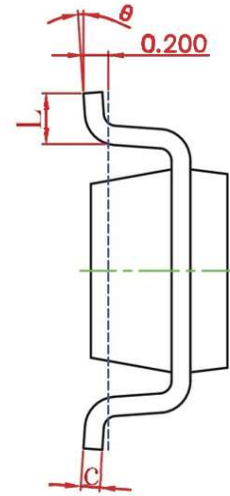
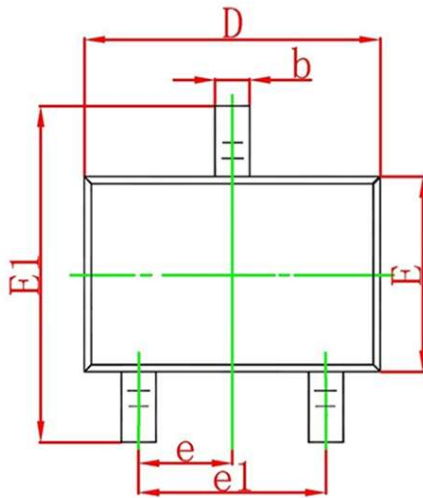
| Type      | Package   | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|-----------|---------|----------------------|-------------------------|----------------------------|---------------|
| MLSK3400A | SOT-23-3L | 3400A   | 3,000                | 45,000                  | 180,000                    | 7"reel        |

| Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)             |                                  |                                                                                      |      |      |      |      |
|--------------------------------------------------------------------------------------|----------------------------------|--------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                                               | Parameter                        | Condition                                                                            | Min  | Typ  | Max  | Unit |
| Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)  |                                  |                                                                                      |      |      |      |      |
| B <sub>V(BR)DSS</sub>                                                                | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                           | 30   | --   | --   | V    |
| I <sub>DSS</sub>                                                                     | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =30V, V <sub>GS</sub> =0V                                            | --   | --   | 1    | μA   |
| I <sub>GSS</sub>                                                                     | Gate-Body Leakage Current        | V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V                                           | --   | --   | ±100 | nA   |
| V <sub>GS(th)</sub>                                                                  | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                             | 0.65 | 0.9  | 1.5  | V    |
| R <sub>DS(on)</sub>                                                                  | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =5.8A                                           | --   | 18   | 28   | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =5.0A                                          | --   | 21   | 33   | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =2.5V, I <sub>D</sub> =4.0A                                          | --   | 30   | 52   | mΩ   |
| Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated) |                                  |                                                                                      |      |      |      |      |
| C <sub>ISS</sub>                                                                     | Input Capacitance                | V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz                                    | --   | 632  | --   | pF   |
| C <sub>OSS</sub>                                                                     | Output Capacitance               |                                                                                      | --   | 58   | --   | pF   |
| C <sub>RSS</sub>                                                                     | Reverse Transfer Capacitance     |                                                                                      | --   | 70   | --   | pF   |
| Switching Characteristics                                                            |                                  |                                                                                      |      |      |      |      |
| Q <sub>g</sub>                                                                       | Total Gate Charge                | V <sub>DS</sub> =15V, I <sub>D</sub> =5.8A, V <sub>GS</sub> =10V                     | --   | 17.3 | --   | nC   |
| Q <sub>gs</sub>                                                                      | Gate Source Charge               |                                                                                      | --   | 2.2  | --   | nC   |
| Q <sub>gd</sub>                                                                      | Gate Drain Charge                |                                                                                      | --   | 2.1  | --   | nC   |
| t <sub>d(on)</sub>                                                                   | Turn-on Delay Time               | V <sub>DD</sub> =15V, I <sub>D</sub> =5.8A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω | --   | 4.4  | --   | nS   |
| t <sub>r</sub>                                                                       | Turn-on Rise Time                |                                                                                      | --   | 28.3 | --   | nS   |
| t <sub>d(off)</sub>                                                                  | Turn-Off Delay Time              |                                                                                      | --   | 16.5 | --   | nS   |
| t <sub>f</sub>                                                                       | Turn-Off Fall Time               |                                                                                      | --   | 26.3 | --   | nS   |
| Source- Drain Diode Characteristics                                                  |                                  |                                                                                      |      |      |      |      |
| V <sub>SD</sub>                                                                      | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =5.8A                                           | --   | --   | 1.2  | V    |

## Typical Operating Characteristics



SOT-23-3L Package information



| Symbol | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 1.050                         | 1.250 | 0.042                | 0.050 |
| A1     | 0.000                         | 0.100 | 0.000                | 0.004 |
| A2     | 1.050                         | 1.150 | 0.042                | 0.046 |
| b      | 0.300                         | 0.500 | 0.012                | 0.020 |
| c      | 0.100                         | 0.200 | 0.004                | 0.008 |
| D      | 2.820                         | 3.020 | 0.112                | 0.120 |
| E      | 1.500                         | 1.700 | 0.060                | 0.068 |
| E1     | 2.650                         | 2.950 | 0.106                | 0.118 |
| e      | 0.950TYP                      |       | 0.037TYP             |       |
| e1     | 1.800                         | 2.000 | 0.071                | 0.079 |
| L      | 0.300                         | 0.600 | 0.012                | 0.024 |
| θ      | 0°                            | 8°    | 0°                   | 8°    |